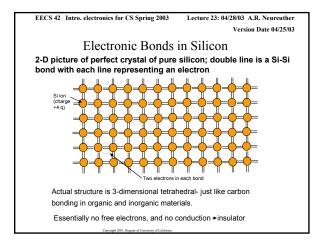
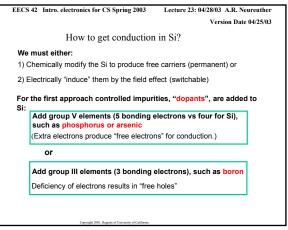
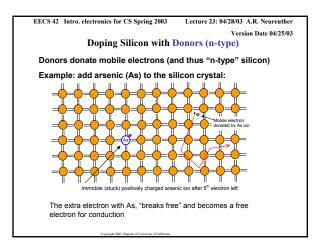


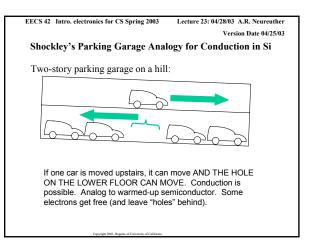
Lecture 23: 04/28/03 A.R. Neureuther
Version Date 04/25/03
① We need a "smart switch," i.e., an electronically controlled switch
^② We need a "gain element" – for example, to make comparators.
MOS transistor
imple in concept
odes, MOS transistor on

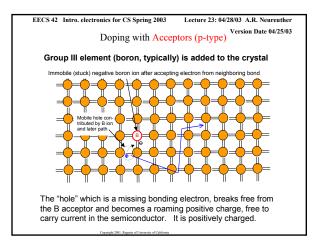


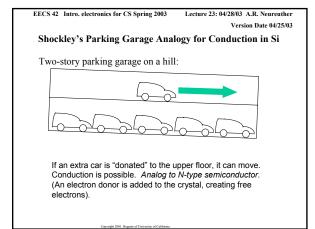
EECS 42 Int	electronics for CS Spring 2003 Lecture 23: 04/28/03 A.R. Neureuther	ecs
	Version Date 04/25/03	
	Game Plan	
We must	/ we begin:	He
1) Chemic	ittle more about semiconductors and pn junction	۱.
2) Electric	r the I vs. V model of diodes and their uses in circuits	2.
For the fir Si:	out MOSFET Operation as a voltage controlled	3.
Add g such	ittle about the MOSFET I-V characteristics	1.
(Extra	ough about the fabrication process for MOS ed circuits so that we can visualize the layout of actual	5.
0	rcuits	
Add g	ith a very brief review of semiconductors and doping	we
Defici		

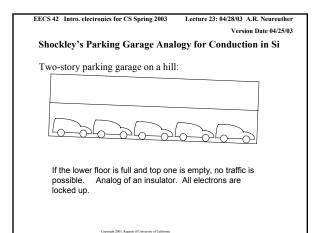


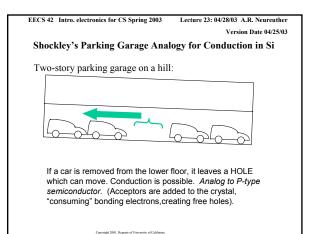


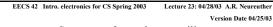












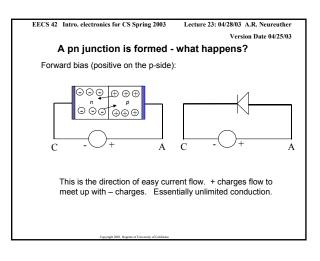
Summary of n- and p-type silicon

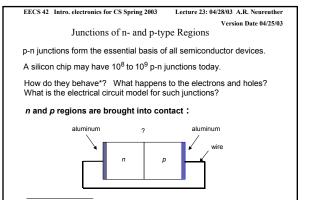
Pure silicon is an insulator. At high temperatures it conducts weakly.

If we add an impurity with extra electrons (e.g. arsenic, phosphorus) these extra electrons are set free and we have a pretty good conductor (n-type silicon).

If we add an impurity with a deficit of electrons (e.g. boron) then bonding electrons are missing (holes), and the resulting holes can move around ... again a pretty good conductor (p-type silicon)

Now what is really interesting is when we join n-type and p-type silicon, that is make a pn junction. It has interesting electrical properties.





*Note that the textbook has a very good explanation.

